

Features

- Low current 0.5mA
- Superior CTR-2000%
- CTR guaranteed 0–70 °C

Applications

- Digital logic ground isolation
- Telephone ring detector
- EIA-RS-232C line receiver
- High common mode noise line receiver
- μ P bus isolation
- Current loop receiver

Description

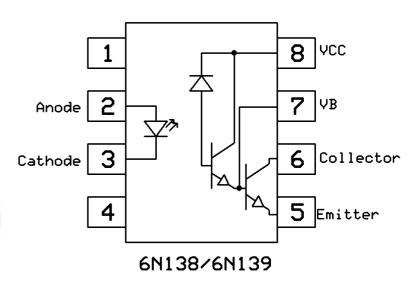
The 6N138 & 6N139 optocouplers consist of an AlGaAs LED optically coupled to a high gain split darlington photodetector.

The combination of a very low input current of 0.5mA and a high current transfer ratio of 2000% makes this family particularly useful for input interface to MOS, CMOS, LSTTL and EIA RS232C, while output compatibility is ensured to CMOS as well as high fan-out TTL requirements.

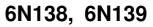
The devices are packaged in an 8-pin DIP package and also available in gullwing (400mil) spacing and surface mount lead forming option.

Package Outline

Schematic



Note: Different lead forming options available. See package dimension.





Absolute Maximum Rating at 25°C

| Symbol | Parameters | Ratings | Units | Notes | | |
|-----------------------|--|---------|------------------|-------|---|--|
| Viso | Isolation voltage | 5000 | V _{RMS} | | | |
| Topr | Operating temperature | | -55 ~ +100 | °C | | |
| Тѕтс | Storage temperature | | -55 ~ +125 | °C | | |
| Tsol | Soldering temperature | | 260 | °C | | |
| Emitter | | | | | | |
| lF | Forward current | | 25 | mA | | |
| I _{FP} | Peak forward current (50% duty, 1ms P.W) | | 50 | 50 mA | | |
| I _{F(TRANS)} | Peak transient current (≤1µs P.W,300pps) | 1 | А | | | |
| V _R | Reverse voltage | 5 | V | | | |
| PD | Power dissipation | 40 | mW | | | |
| Detector | | | | • | • | |
| P _D | Power dissipation | 100 | mW | | | |
| V _{EBR} | Emitter-Base reverse voltage | | 0.5 | V | | |
| lo | Output Current | 60 | mA | | | |
| W | Output valte se | 6N138 | -0.5 to 7 | V | | |
| Vo | Output voltage | 6N139 | -0.5 to 18 | V | | |
| Vcc | Cumply yellogo | 6N138 | -0.5 to 7 | V | | |
| | Supply voltage | 6N139 | -0.5 to 18 | V | | |



Electrical Characteristics $T_A = 0 - 70 \, \text{C}$, $V_{CC} = 4.5 \text{V}$ (unless otherwise specified).

Emitter Characteristics

| Symbol | Parameters | Test Conditions | Min | Тур | Max | Units | Notes |
|-------------------------|--|-----------------------|-----|------|-----|-------|-------|
| VF | Forward voltage | I _F = 16mA | - | 1.45 | 1.6 | ٧ | |
| IR | Reverse Current | V _R = 5V | - | - | 5 | μΑ | |
| $\Delta V_F/\Delta T_A$ | Temperature coefficient of forward voltage | I _F =16mA | - | -1.8 | - | mV/℃ | |

Detector Characteristics

| Symbol | Parameters | | Test Conditions | Min | Тур | Max | Units | Notes |
|------------------------|---------------------------|-------|--|-----|-------|-----|-------|-------|
| la | Logic High Output | 6N139 | I _F =0mA, V _O =V _{CC} =18V, | | 0.008 | 80 | μΑ - | |
| I _{ОН} Curren | Current | 6N138 | if=UIIA, VO=VCC=10V, | - | - | 200 | | |
| Iccl | Logic Low Supply Current | | I _F =1.6mA, V _O =Open, V _{CC} =18V | 1 | 0.5 | 1.4 | mA | |
| Іссн | Logic High Supply Current | | I _F =0mA, V _O =Open, V _{CC} =18V | - | 0.04 | 8 | μΑ | |

Transfer Characteristics

| Symbol | Parameters | | Test Conditions | Min | Тур | Max | Units | Notes |
|----------|--|--------|--|-----|------|-----|-------|-------|
| | TR Current Transfer Ratio | 6N139 | I _F =0.5mA, V _O =0.4V, | 400 | 2500 | - | | |
| CTR | | 6N138 | 1 10 1 1 0 5 1 | 300 | 2000 | - | % | |
| | | 6N139 | I _F =1.6mA, V _O =0.5V, | 500 | 2000 | - | | |
| | | | I _F = 0.5mA, I _O = 2mA | - | 0.04 | 0.4 | | |
| | La sia Laur Outro t | CNITOO | I _F = 1.6mA, I _O = 8mA | - | 0.08 | 0.4 | | |
| V_{OL} | V _{OL} Logic Low Output Voltage | 6N139 | I _F = 5mA, I _O = 15mA | - | 0.11 | 0.4 | ٧ | |
| | | | I _F = 12mA, I _O = 24mA | - | 0.16 | 0.4 | | |
| | | 6N138 | I _F = 1.6mA, I _O = 4.8mA | - | 0.05 | 0.4 | | |



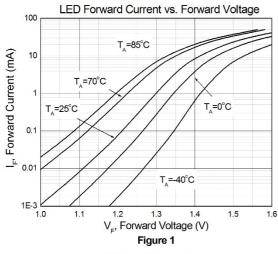
Electrical Characteristics $T_A = 0 - 70 \, \text{C}$, $V_{CC} = 5V$ (unless otherwise specified).

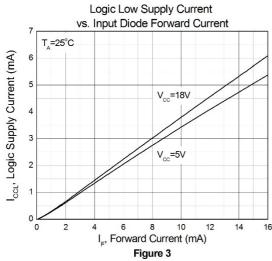
Switching Characteristics

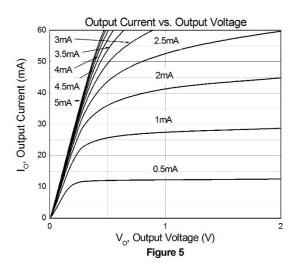
| Symbol | Paramete | ers | Test Cond | litions | Min | Тур | Max | Units | Notes |
|-----------|------------------------|--------|--|------------------------------------|-------|---------|-----|-------|-------|
| | | 6N139 | I _F = 0.5mA, | | - | - | 30 | μs | |
| | | | R _L = 4.7k | T _A = 25 ⁰ C | - | 4.8 | 25 | | |
| _ | High to Low | | I _F = 12mA, | | - | - | 2 | | |
| T_{PHL} | Propagation Delay | | R _L = 250 | T _A = 25 ⁰ C | - | 0.2 | 1 | | |
| | | 6N138 | I _F = 1.6mA, | | - | - | 15 | | |
| | | | R _L = 2.2k | T _A = 25 ⁰ C | - | 1.35 | 10 | | |
| | | CNIAGO | I _F = 0.5mA, | | - | - | 90 | μs | |
| | | | R _L = 4.7k | T _A = 25 ⁰ C | - | 15 | 60 | | |
| _ | Low to High | 6N139 | I _F = 12mA, | | - | - | 10 | | |
| T_PLH | Propagation Delay | | R _L = 250 | T _A = 25 ⁰ C | - | 1.6 | 7 | | |
| | | CNITOO | I _F = 1.6mA, | | - | - | 50 | | |
| | | 6N138 | R _L = 2.2k | T _A = 25 ⁰ C | - | 7.6 | 35 | | |
| CM | Common Mode Transient | | IF = 0mA, VCM = 10V _{P-P} , | | 1 000 | | | | |
| СМн | Immunity at Logic High | | T _A = 25 °C,R _L = 2. | 2kΩ | 1,000 | - | - | V/μs | |
| CML | Common Mode Transient | | I _F = 1.6mA, VCM | = 10V _{P-P} , | | 1,000 - | | ν/μδ | |
| CIVIL | Immunity at Logic Low | | $T_A = 25 ^{\circ}\text{C}, R_L = 2.$ | 2kΩ | 1,000 | - | - | | |

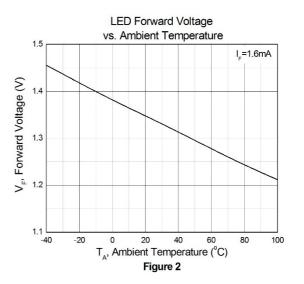


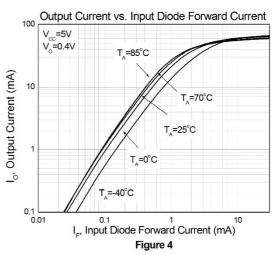
Typical Characteristic Curves

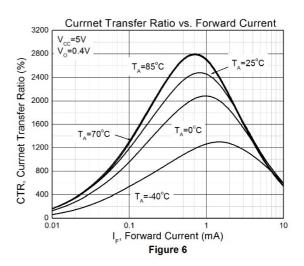




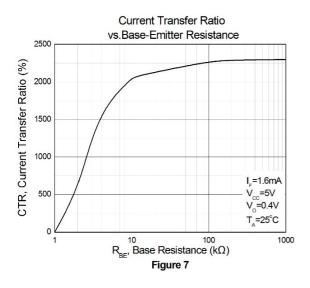


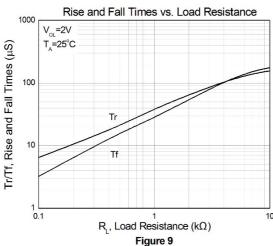


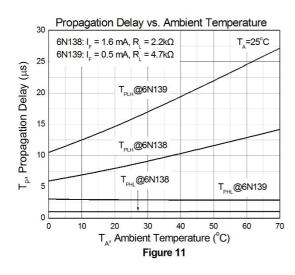


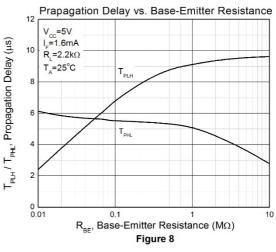


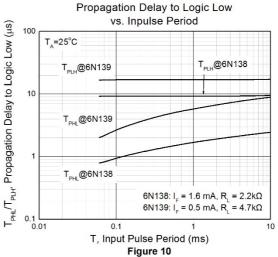


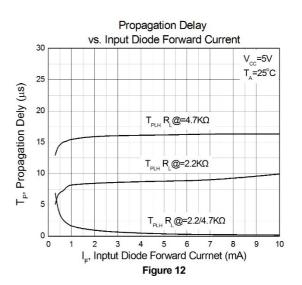






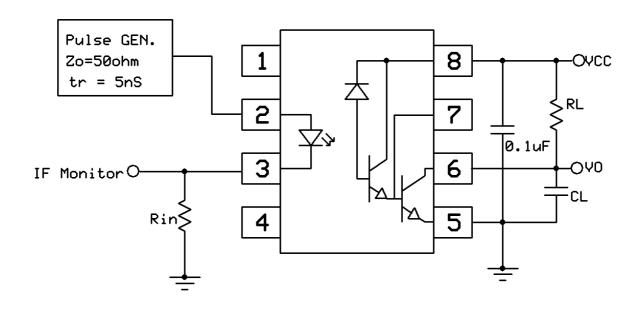


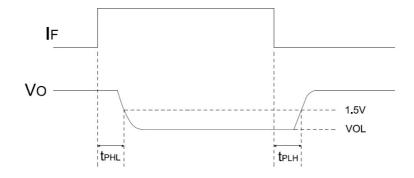






Test Circuits

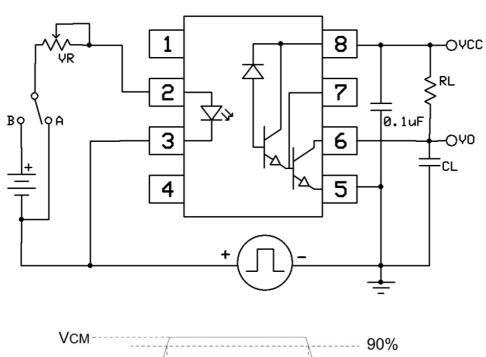


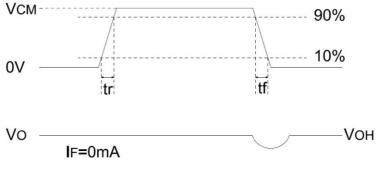


Switching Time Test Circuit



Test Circuits





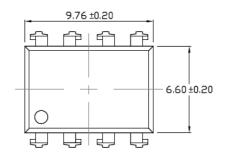


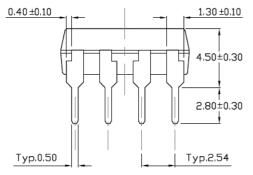
CMR Test Circuit

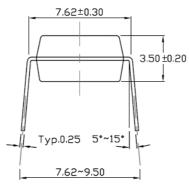


Package Dimension Dimensions in mm unless otherwise stated

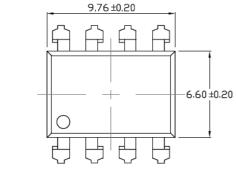
Standard DIP - Through Hole

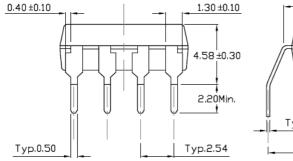






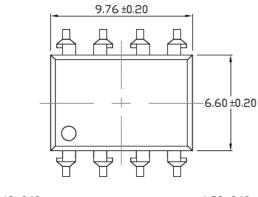
Gullwing (400mil) Lead Forming – Through Hole (M Type)

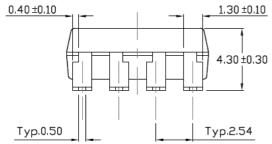


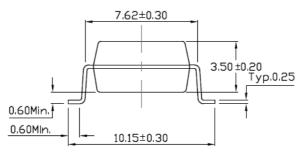




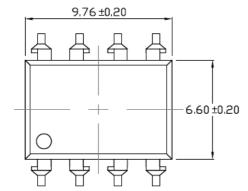
Surface Mount Lead Forming (S Type)

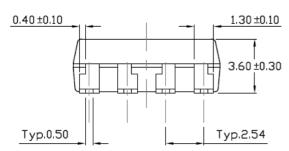


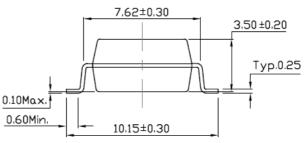




Surface Mount (Low Profile) Lead Forming (SL Type)

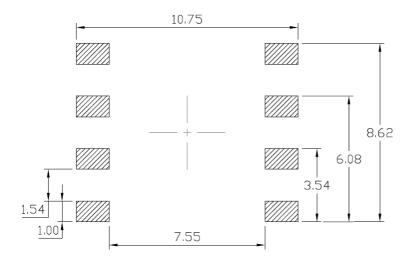




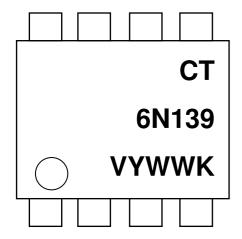




Recommended Solder Mask Dimensions in mm unless otherwise stated



Device Marking



CT : Denotes "CT Micro"6N139 : Product NumberV : VDE Option

Y : Fiscal Year
WW : Work Week

K : Production Code



Ordering Information

6N13X(V)(Y)(Z)

X = Part No. (8 or 9)

V = VDE Option (V or None)

Y = Lead form option (S, SL, M or none)

Z = Tape and reel option (T1, T2 or none)

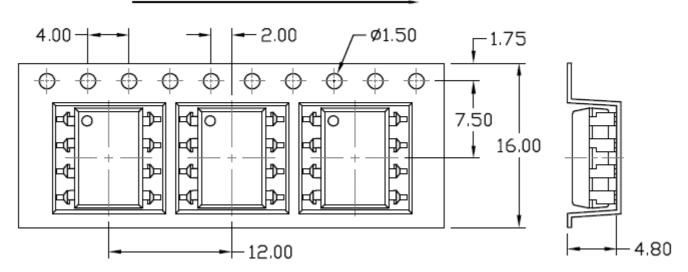
| Option | Description | Quantity |
|--------|--|-----------------|
| None | Standard 8 Pin Dip | 40 Units/Tube |
| M | Gullwing (400mil) Lead Forming | 40 Units/Tube |
| S(T1) | Surface Mount Lead Forming – With Option 1 Taping | 1000 Units/Reel |
| S(T2) | Surface Mount Lead Forming – With Option 2 Taping | 1000 Units/Reel |
| SL(T1) | Surface Mount (Low Profile) Lead Forming- With Option 1 Taping | 1000 Units/Reel |
| SL(T2) | Surface Mount (Low Profile) Lead Forming- With Option 2 Taping | 1000 Units/Reel |



Carrier Tape Specifications Dimensions in mm unless otherwise stated

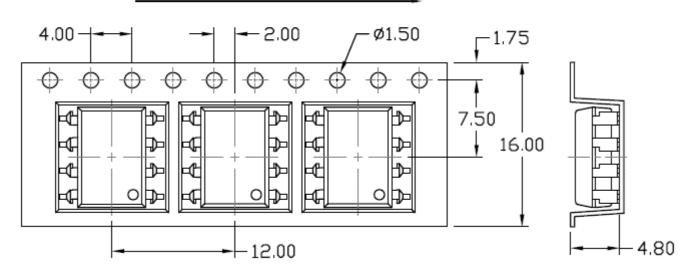
Option S(T1) & SL(T1)

Input Direction



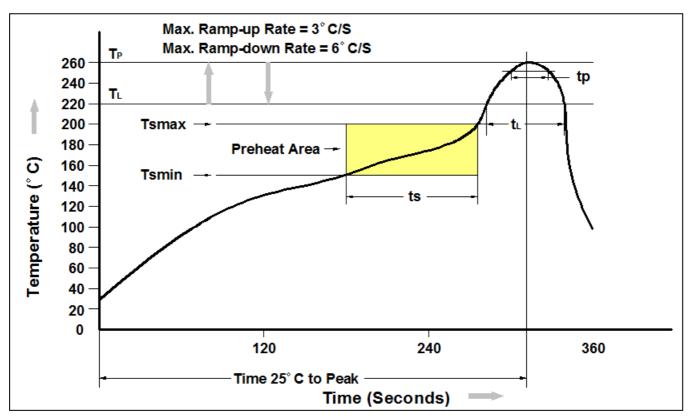
Option S(T2) & SL(T2)

Input Direction

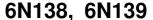




Reflow Profile



| Profile Feature | Pb-Free Assembly Profile |
|---|--------------------------|
| Temperature Min. (Tsmin) | 150℃ |
| Temperature Max. (Tsmax) | 200℃ |
| Time (ts) from (Tsmin to Tsmax) | 60-120 seconds |
| Ramp-up Rate (t _L to t _P) | 3°C/second max. |
| Liquidous Temperature (TL) | 217℃ |
| Time (t _L) Maintained Above (T _L) | 60 – 150 seconds |
| Peak Body Package Temperature | 260 ℃ +0 ℃ / -5 ℃ |
| Time (t _P) within 5 °C of 260 °C | 30 seconds |
| Ramp-down Rate (T _P to T _L) | 6°C/second max |
| Time 25℃ to Peak Temperature | 8 minutes max. |





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